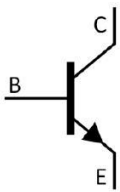


SOT-323 NPN Silicon NPN transistor in a SOT-323 Plastic Package.

- $V_{ce(sat)}=0.3V_{max}$
Collectoe to emitter saturation voltage $V_{ce(sat)}=0.3V_{max}$ Excellent lineality of DC forward current gain,Supper mini package for easy mounting.

For hybrid IC,small type machine low frequency voltage amplify application.

⌚ ⚡ ⚡ / Equivalent Circuit



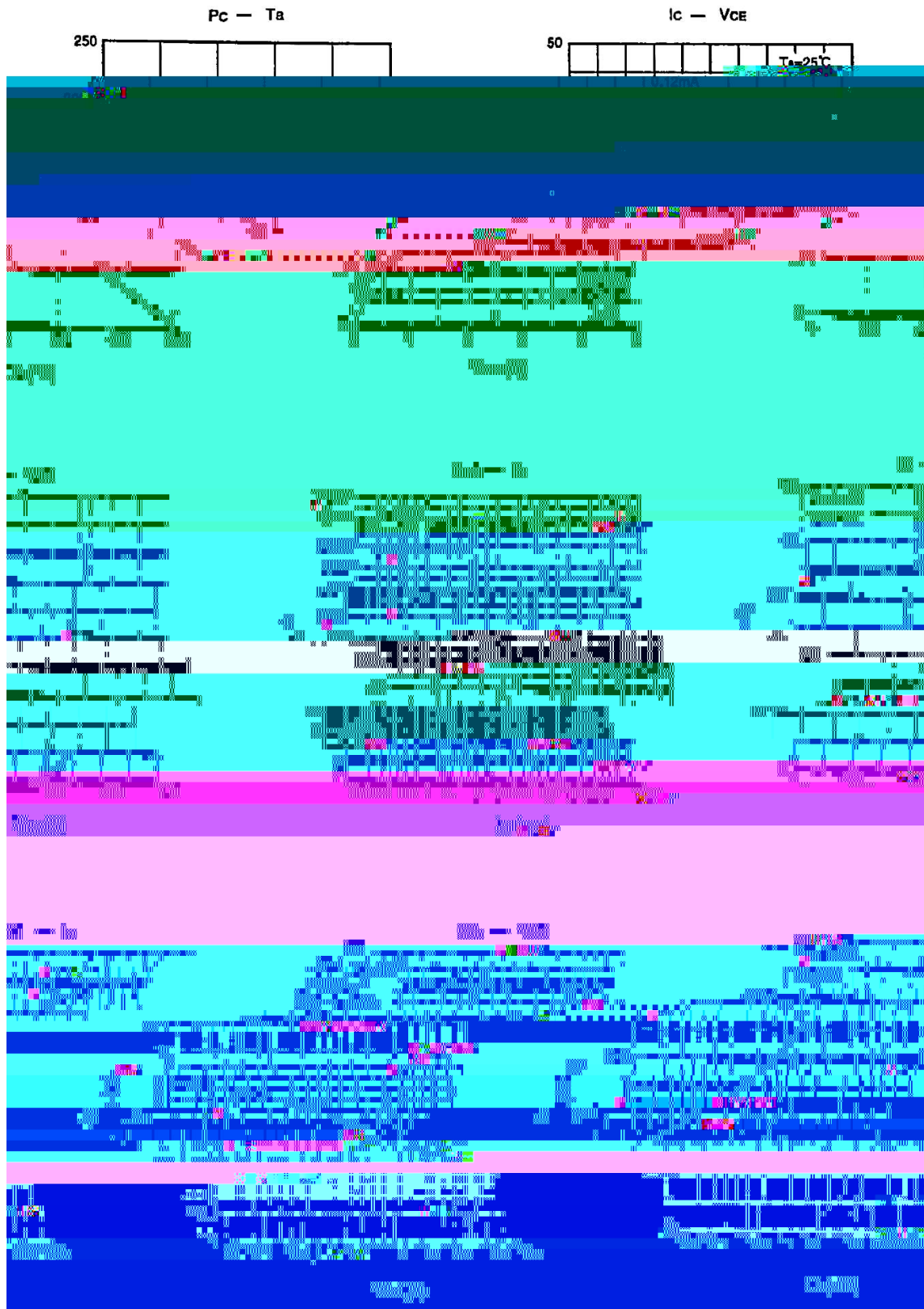
PIN1 Emitter PIN 2 Base PIN 3 Collector

⌚ ⚡ ⚡ / Marking

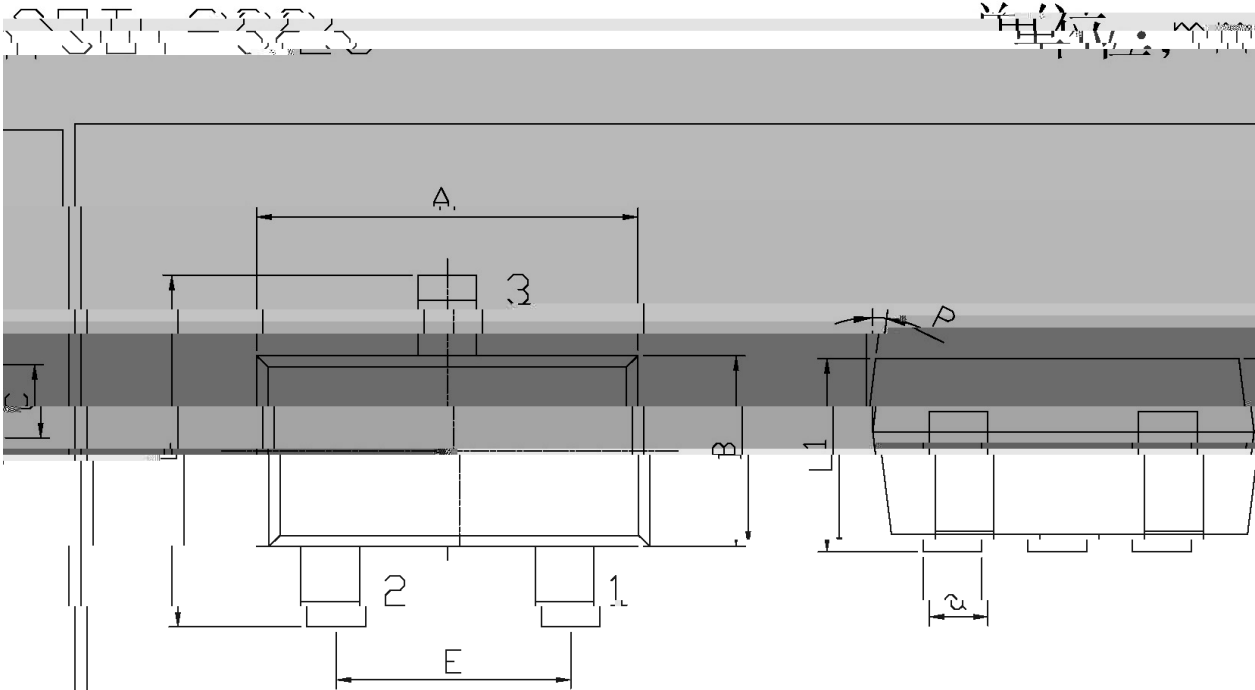
h_{FE} Classifications	Q	R	S	T
Symbol				
h_{FE} Range				

Parameter	Symbol		Rating	Unit
Collector to Base Voltage	V_{CBO}		50	V
Collector to Emitter Voltage	V_{CEO}		50	V
Emitter to Base Voltage	V_{EBO}		6	V
Collector Current - Continuous	I_C	2SC4155	0.1	A
		2SC4155A	0.2	
Collector Power Dissipation	P_C		150	mW

电气特性 / Electrical Characteristic Curve

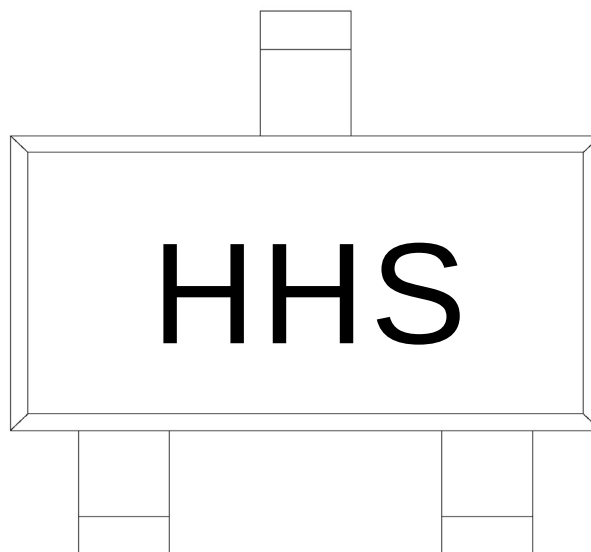


Package Dimensions



Dimensions In Millimeters				Dimensions In Millimeters			
Symbol	Min	Max		Symbol	Min	Max	
A	1.95	2.35		C	0.30	0.50	
L	2.00	2.2		L	0.85	1.15	
E	1.20	1.40			0.20	0.40	

4. 标记 / Marking Instructions



H

H

S h_{FE}

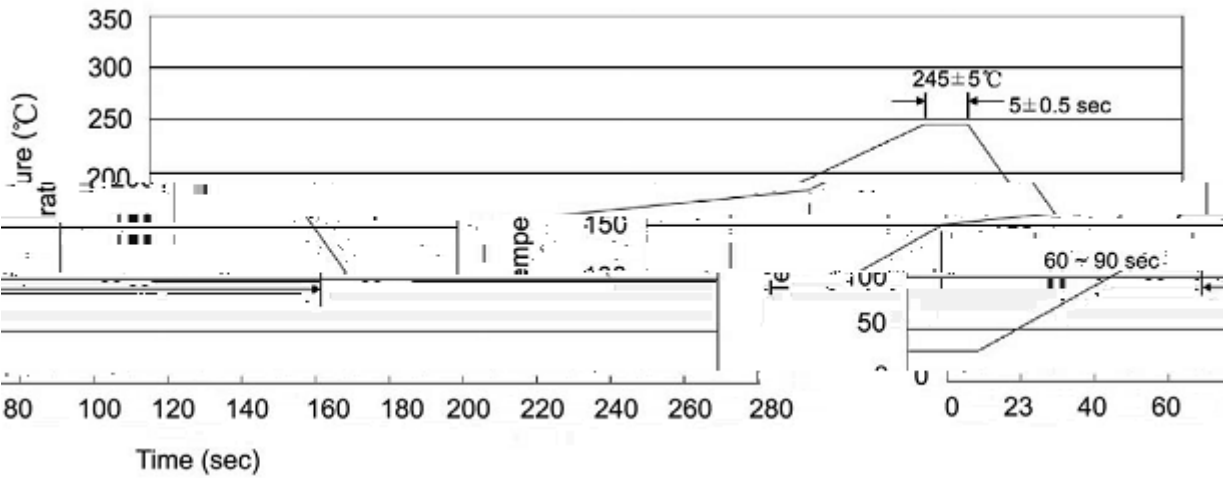
Note:

H: Company Code.

H: Product Type.

S: h_{FE} Classifications Symbol

Whp shudwxuh Suriloh i ru LU Uhior z Vroghulqj+Se0l uhh,



Note:

- | | | | | | |
|---|-------|-----|----|-----------|---|
| 1 | 25 | 150 | 60 | 90sec; | 1.Preheating:25~150 , Time:60~90sec. |
| 2 | 245±5 | | | 5±0.5sec; | 2.Peak Temp.:245±5 , Duration:5±0.5sec. |
| 3 | | | 2 | 10 /sec. | 3. Cooling Speed: 2~10 /sec. |

Resistance to Soldering Heat Test Conditions

260±5 10±1 sec. Temp.:260±5 Time:10±1 sec

Packaging SPEC.

/ REEL

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm ³)		
	Units/Reel 只/卷盘	Reels/Inner Box 卷盘/盒	Units/Inner Box 只/盒	Inner Boxes/Outer Box 盒/箱	Units/Outer Box 只/箱	Reel	Inner Box 盒	Outer Box 箱
SOT-323	3,000	10	30,000	6	180,000	7 ×8	180×120×180	390×385×205

Notices